

Figure 1: Experimental Setup for determining the specific heat capacity of a metal ball.

Purpose

To determine the specific heat capacity of a solid by the method of mixtures

theory

The heat capacity C of an object (e.g. metal ball) is the proportionality constant between an amount of heat and the change in temperature that the heat produced in the object. Thus, $Q = C(T_f - T_i)$, where T_i and T_f are the initial and final temperatures of the object. Two objects made of the same material, say marble, will have heat capacities proportional to their masses. It is therefore convenient to define a “heat capacity per unit mass” or specific heat c that refers not to an object but to unit mass of the material of which the object is made and is expressed in joule per kilogram per Kelvin ($\text{J kg}^{-1}\text{K}^{-1}$). The specific heat capacity equation then becomes $Q = mc(T_f - T_i)$, where m is the mass of the object.

Equipment/ Materials/ Apparatus

Y

- Solid (e.g. metal ball) of reasonable size
- Calorimeter with an insulation, outer jacket and stirrer
- Thermometer (reading up to 0.1°C)
- Heater
- Thread
- Sensitive balance
- Beaker

observation

11. Record your observation.
12. Record your observations

- | | |
|---|-------------------------------|
| i. Mass of solid | $m_1 =$ |
| ii. Mass of empty calorimeter | $m_2 =$ |
| iii. Mass of calorimeter + water | $m_3 =$ |
| iv. Initial temperature of water in calorimeter | $T_i =$ |
| v. Temperature of the hot solid | $100^\circ\text{C} =$ |
| vi. Temperature of mixture | $T_f =$ |
| vii. Rise in temperature of water and calorimeter | $(T_f - T_i)^\circ\text{C} =$ |
| viii. Fall in temperature of hot solid | $(100 - T_i)^\circ\text{C} =$ |

calculation

13. Calculate the specific heat capacity of the solid.

Let S.H.C of solid	=	c
Also, let S.H.C of calorimeter	=	c_1
And let S.H.C of water	=	c_w
Heat lost by solid	=	$m_1 c (100 - T_f)$
Heat gained by water	=	$(m_3 - m_2) c_w (T_f - T_i)$
Heat gained by calorimeter	=	$m_2 c_1 (T_f - T_i)$
Total heat gained	=	$(T_f - T_i) [(m_3 - m_2) c_w + m_2 c_1]$

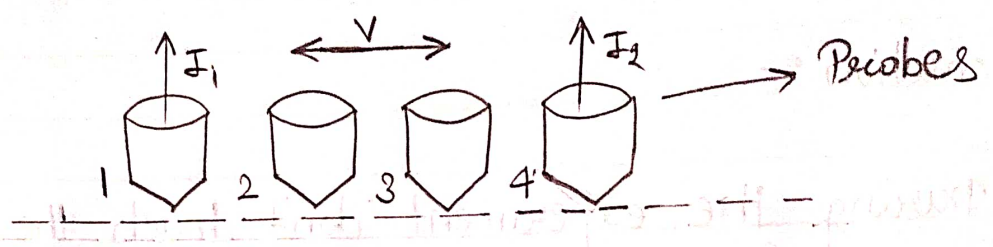
But heat lost	=	Heat gained
$m_1 c (100 - T_f)$	=	$(T_f - T_i) [(m_3 - m_2) c_w + m_2 c_1]$
c	=	$\frac{(T_f - T_i) [(m_3 - m_2) c_w + m_2 c_1]}{m_1 (100 - T_f)}$

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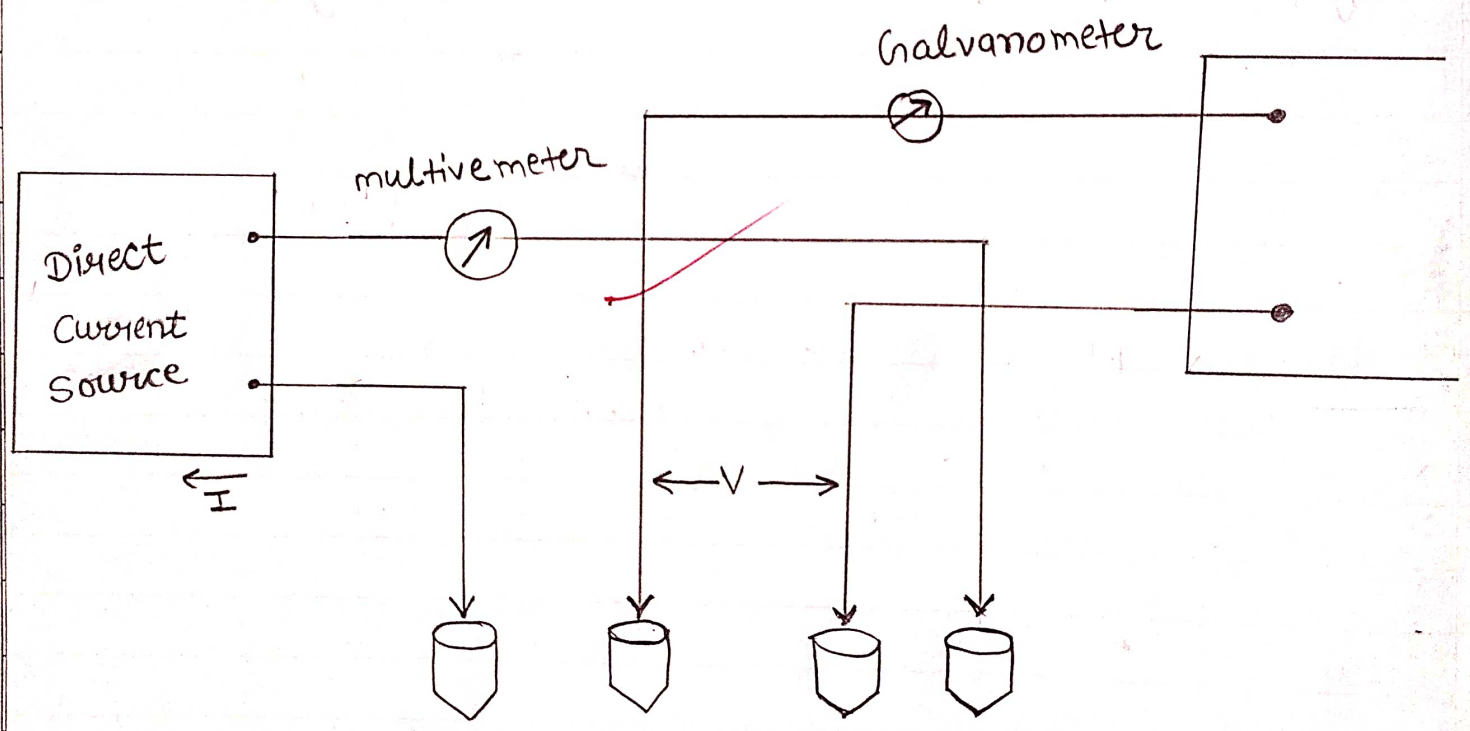
Conclusion

The specific heat capacity of the object =

$\rho = \frac{RA}{L}$
 $R = \frac{\rho L}{A}$
 $\rho = \frac{RA}{L}$



Method for the four Probe Resistivity



Circuit for resistivity measurement

Expt. No. 2.

Object :- To determine the band gap of semi-conductor using four probe method.

Apparatus :- Four probe set up, thermometer, oven, Ge-chip, Connecting wire

formula used -

$$\text{Slope} = \frac{\ln \rho}{1/T} = \frac{E_g}{2K}$$

$$E_g = 2KT \ln \rho \quad \text{where } E_g = \text{Energy band gap}$$

$$T = \text{Temp.}$$

$$\rho = \rho_0$$

$$G \neq \left(\frac{W}{WS} \right)$$

$$\rho = \text{resistivity}$$

$$K = \text{Boltzmann's Constant}$$

$$E_g = 2K \times 2.303 \times 10^3 \times \text{Slope}$$

slope = slope of graph b/w $\log_{10} \rho$ and $10^3/T$

Theory :- The property of bulk material used for the if a bication at transition and other Semiconductor device are essential in determining the characteristics at the complete device.

Resistivity and life time (at minority carriers) measurements are generally their suitability.

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The resistivity in particular may be measured accurately since its value is critical in many device.

Four Probe method —

In four probe method four sharp probes are placed on a flat surface of the material to be the outer measurement current is passed through the outer electrodes and the floating potential is measured across the linear pairs.

The semiconductor may be considered to the semi-co-finite volume to prevent minority carrier injection and make good contacts the surface on which the probe rest may be mechanically lapped.

Observation :-

(i) Distance b/w probe (S) = 0.200 cm

(ii) Thickness of the crystal (N) = 0.050 cm

Calculation :-

$$g = \frac{g_0}{G_T (\omega/s)} \quad \text{where } g_0 = \frac{V}{I} \times 2\pi f$$
$$I = 5 \text{ mA} = 5 \times 10^{-5} \text{ Amp}$$

and $G_T (\omega/s) = \frac{2S}{w} \log_e^2 = 5.544$

distance b/w probe $S = 2 \text{ mm} = 0.2 \text{ cm} = 2 \times 10^{-3} \text{ m}$

Thickness of crystal $w = 0.5 \text{ mm} = 0.05 \text{ cm} = 0.5 \times 10^{-3} \text{ m}$

$$\textcircled{1} \quad g_0 = \frac{0.286}{5 \times 10^{-3} \times 100} \times 2 \times 3.14 \times 2 \times 10^{-3} = 0.718$$

$$g = \frac{g_0}{G_T (\omega/s)} = \frac{0.716}{5.544} = 0.129$$

$$\textcircled{2} \quad g_0 = 0.316 \times 2.512 = 0.793 \quad g = 0.143$$

$$\textcircled{3} \quad g_0 = 0.344 \times 2.512 = 0.864 \quad g = \frac{g_0}{G_T (\omega/s)} = \frac{0.864}{5.554} = 0.156$$

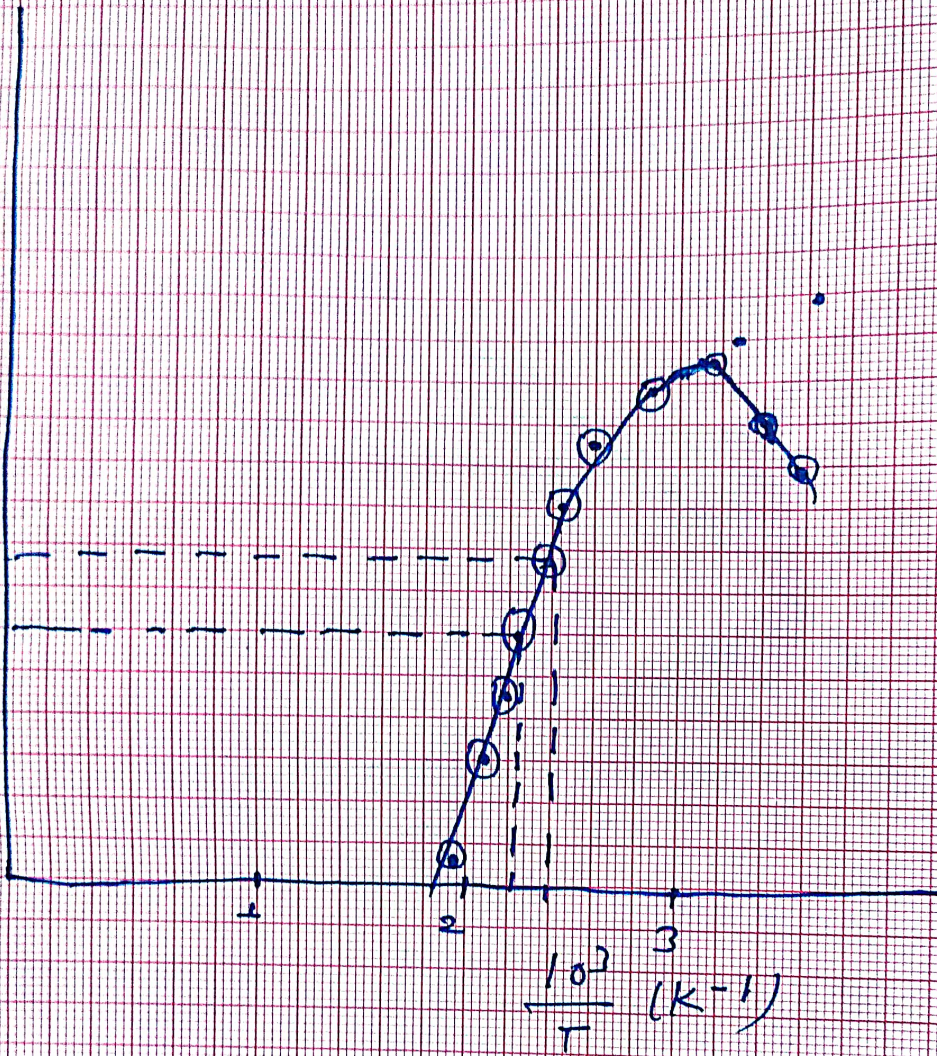
$$\textcircled{4} \quad g_0 = 0.379 \times 2.512 = 0.952 \quad g = \frac{g_0}{G_T (\omega/s)} = \frac{0.952}{5.554} = 0.172$$

$$\textcircled{5} \quad g_0 = 0.410 \times 2.512 = 1.03 \quad g = \frac{1.03}{5.544} = 0.186$$

$$\textcircled{6} \quad g_0 = 0.437 \times 2.512 = 1.09 \quad g = \frac{1.09}{5.544} = 0.196$$

$$\textcircled{7} \quad g_0 = 0.461 \times 2.512 = 1.16 \quad g = \frac{1.16}{5.554} = 0.209$$

$\log_{10} \rho$



Result :-

The resistivity of the given semiconductor varies with temp. according to obtained graph.
The energy band gap comes out to be.

$$E_g = 1.4103138 \text{ eV}$$

S. No.	Temp °C	Volt V	Temp (T in K)	ρ Ohm-cm	$T^{-1} \times 10^3$	$\text{Log}_{10} \rho$
1.	30	215	303	9.53	3.30	0.97
2.	40	215	313	9.53	3.19	0.97
3.	50	213	323	9.44	3.10	0.97
4.	60	203	333	9.00	3.00	0.95
5.	70	179	343	7.93	2.92	0.89
6.	80	156	353	6.91	2.82	0.83
7.	90	126	363	5.58	2.75	0.74
8.	100	109	373	4.83	2.68	0.68
9.	110	088	383	3.90	2.61	0.59
10.	120	066	393	2.92	2.54	0.46
11.	130	047	403	2.08	2.48	0.31
12.	140	035	413	1.55	2.42	0.19
13.	150	028	423	1.24	2.36	0.09
14.	160	019	433	0.84	2.25	-0.07

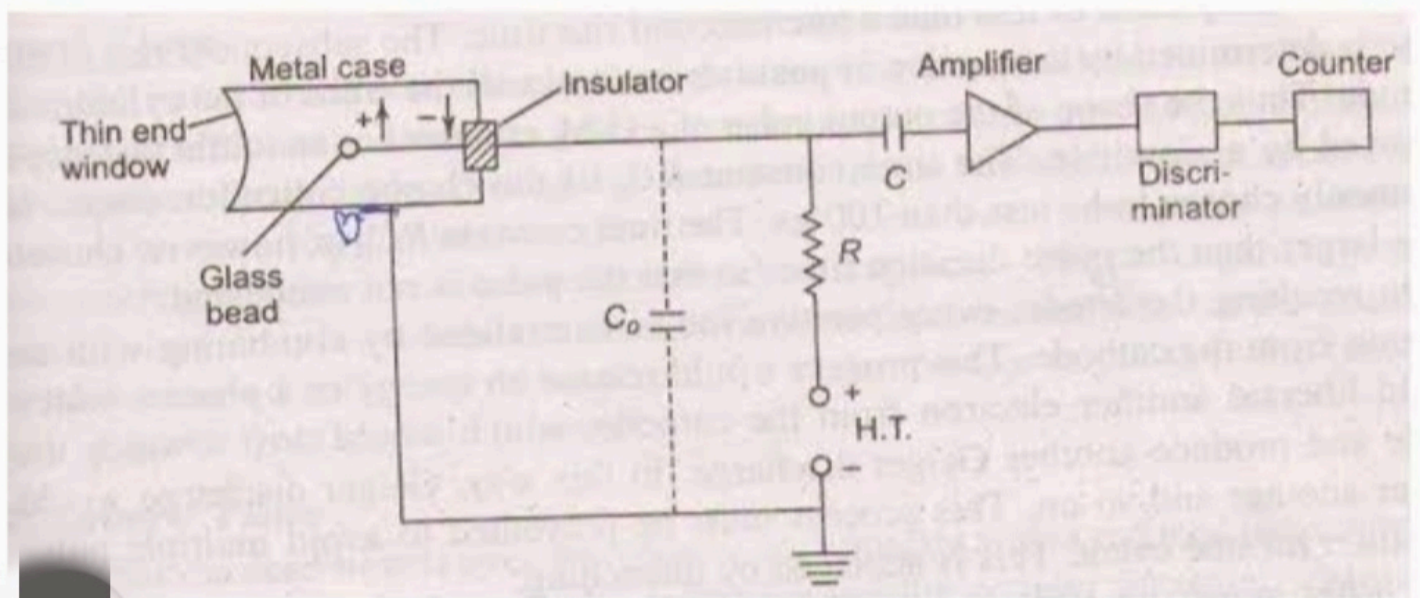


Fig.- GM COUNTER

Object :- Study of the characteristics of a G.M Tube

Apparatus :- G.M tube, G.M detector, source holder, bench, Connecting cable.

Theory :- plateau length (VPL) = $V_2 - V_1$
 operating voltage $V_0 = \frac{V_2 + V_1}{2}$

The slope of the plateau is given by

$$\frac{N_2 - N_1}{N_1} \times \frac{100}{V_2 - V_1} \times 100\%$$

Observation :-

S.No	Voltage	Counts 30 sec (No) without Source	Count 30 sec with Source N	Corrected counts. (N - N ₀)
1	325	0	0	0
2	350	18	1370	1352
3	375	23	1627	1604
4	400	24	1631	1605
5	425	26	1635	1609
6	450	30	1641	1611
7	475	32	1647	1615
8	500	37	1655	1618
9	525	30	1681	1651
10	550	29	1685	1655
11	575	18	2645	2627
12	600	38	3300	3262
13.	625	35	3322	3287

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Calculation :-

$$V_1 = 375 \quad V_2 = 550 \quad (\text{from graph})$$

$$\text{plate length} = V_2 - V_1 = 550 - 375 \\ = 175 \text{ V}$$

$$\text{operating voltage} = \frac{V_2 + V_1}{2} \\ = 463.5 \text{ V} \\ = 463 \text{ V}$$

Slope of plateaus is given as

$$\frac{N_2 - N_1}{N_2} \times \frac{100}{V_2 - V_1} \times 100\%$$

$$\frac{1656 - 1604}{1604} \times \frac{100}{175} \times 100\%$$

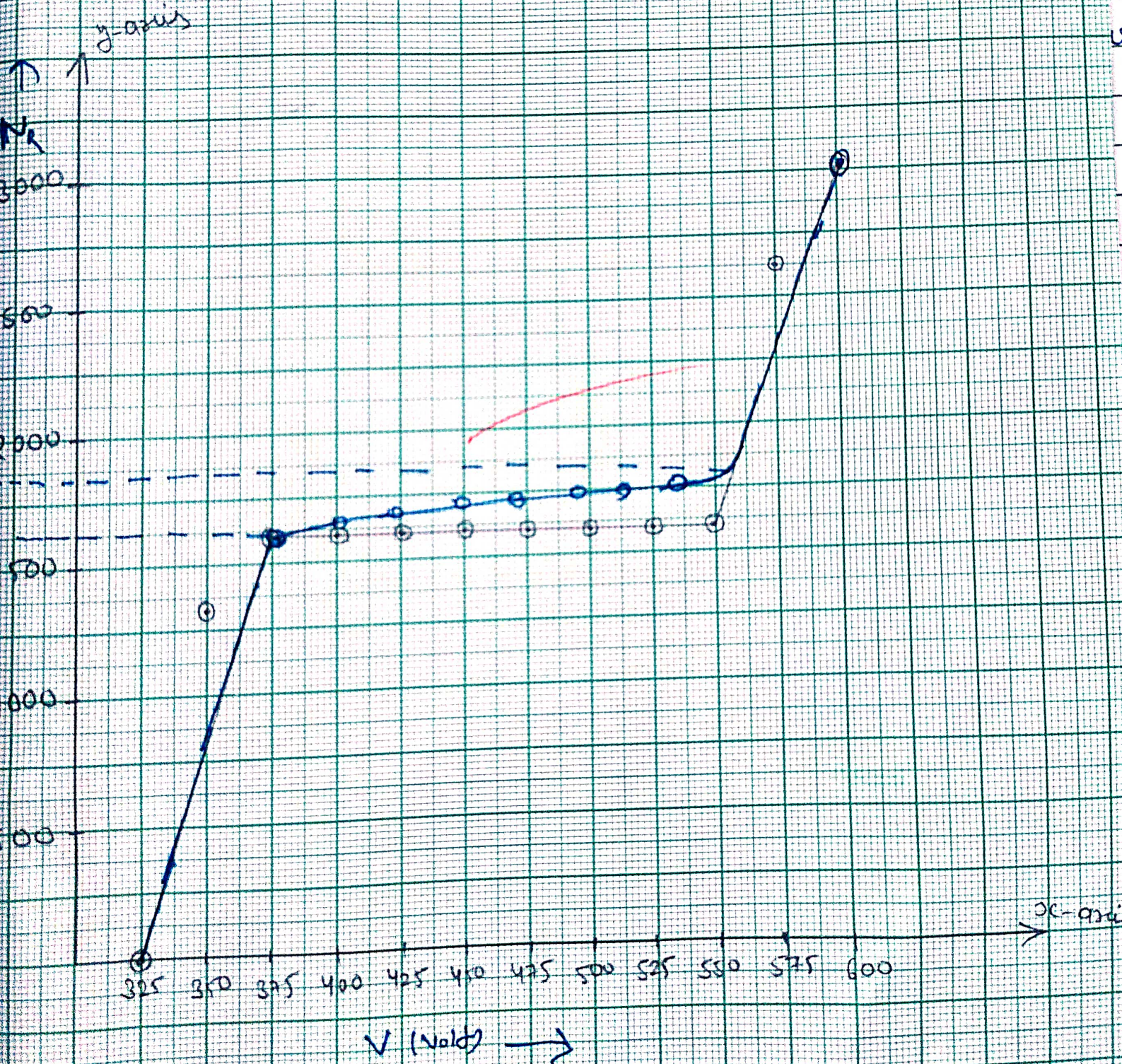
$$= 1.85 \times 10^{-4} \times 10^4$$

$$= 1.85\%$$

Scale :-

$$x\text{-axis} = 1 \text{ Unit} = 25$$

$$y\text{-axis} = 2 \text{ Unit} = 500$$



Result :- The operating voltage (from graph) = 463V
and slope of plateau is = 1.85%.

Precaution :-

1. Do not touch wire after power on
2. using plucker to get out the source from source holder.

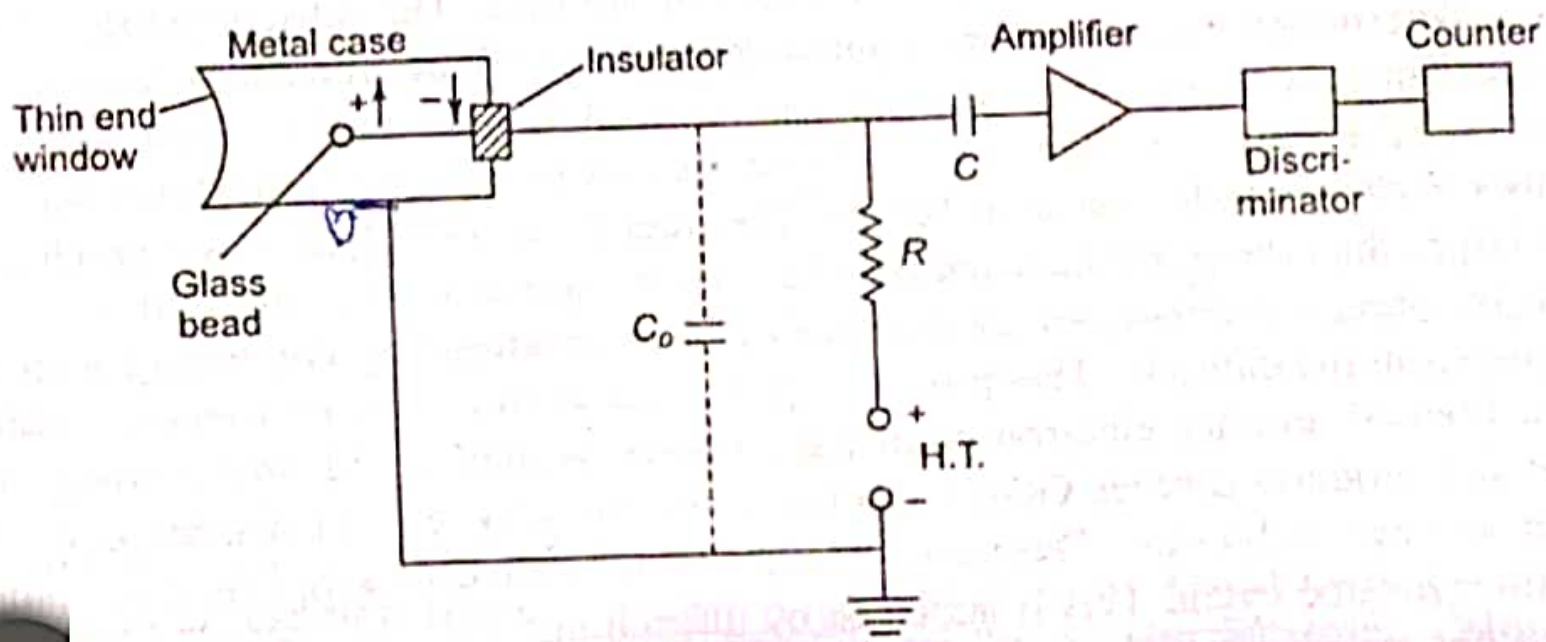


Fig.- GM COUNTER

Object :- To verify the inverse square relationship b/w the distance and radiation.

Apparatus :- Gm Counter, Gm detector stand, Gm detector with connecting cable, A ~~gamma~~ (Beta) Source.

Theory :- The inverse square law says is that if we double the distance b/w source and detector intensity goes down by a factor of four if we triple the distance intensity would decrease by factor of nine and soon. As a result if we move to distance of a away from the detector scale of the G.M Counter then the intensity of radiation decreases by a factor.

Product of $c = R \cdot d^2$ is constant

Observation :- operating voltage 463V
Table

S.No	distance in cm (d)	Counts N is 30 sec	Net Count R (Rate)	in Product	$\frac{1}{d^2} (\ln L)$ m ²
1	2	898	29.93	100	2500
2	3	665	22.57	200	1100
3	4	521	17.37	348	625
4	5	417	13.9	378	400
5	6	352	11.73	422	278
6	7	250	8.33	408	204

Calculation

(i) at $d = 2 \text{ cm}$

$$\frac{1}{d^2} = \frac{1}{4 \times 10^{-4}} = 2500 \quad \left(\text{in } \frac{1}{\text{m}^2} \right)$$

(ii) at $d = 3$

$$\frac{1}{d^2} = \frac{1}{9 \times 10^{-4}} = 1100$$

(iii) at $d = 4$; $\frac{1}{d^2} = \frac{1}{16 \times 10^{-4}} = 625$

(iv) at $d = 5$

$$\frac{1}{d^2} = \frac{1}{25 \times 10^{-4}} = 400$$

(v) at $d = 6$

$$\frac{1}{d^2} = \frac{1}{36 \times 10^{-4}} = 278$$

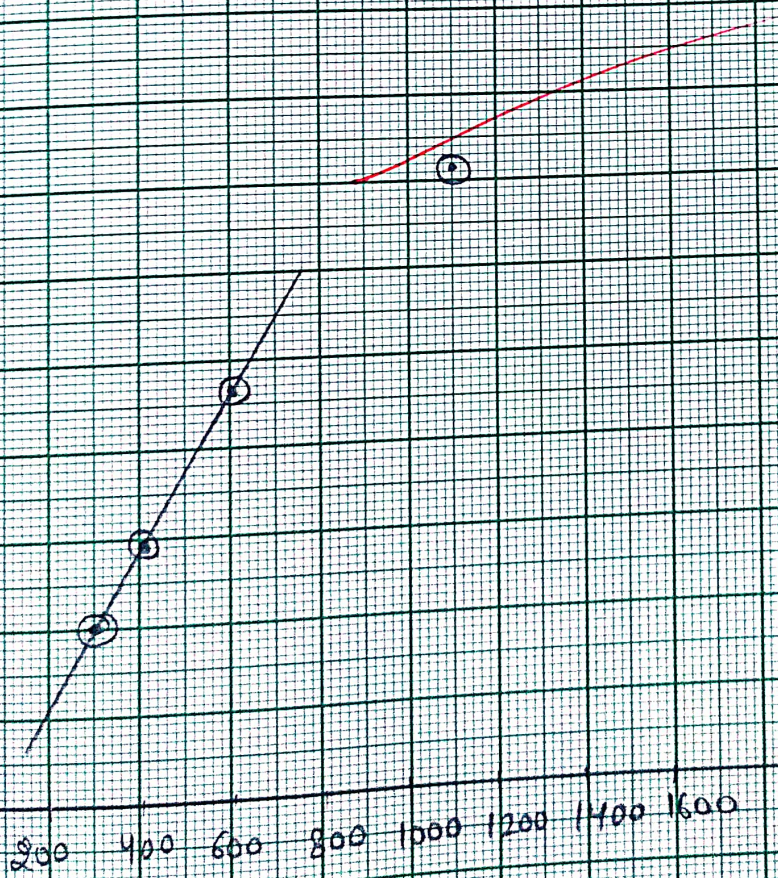
Scale :-

Small division on x-axis = 20 $\frac{1}{\text{km}}$

Small division on y-axis = 0.2

y-axis

22
26
24
22
20
18
16
14
12
10



x-axis

$\left(\frac{1}{d^2}\right) \rightarrow$

Result :- plot a graph of net scale (R) as distance (d) and product of $(c = R d^2)$ transformation $1/d^2$ shown in table.

Precaution :-

- (i) Do not touch the detector wire of for power cuppel is one.

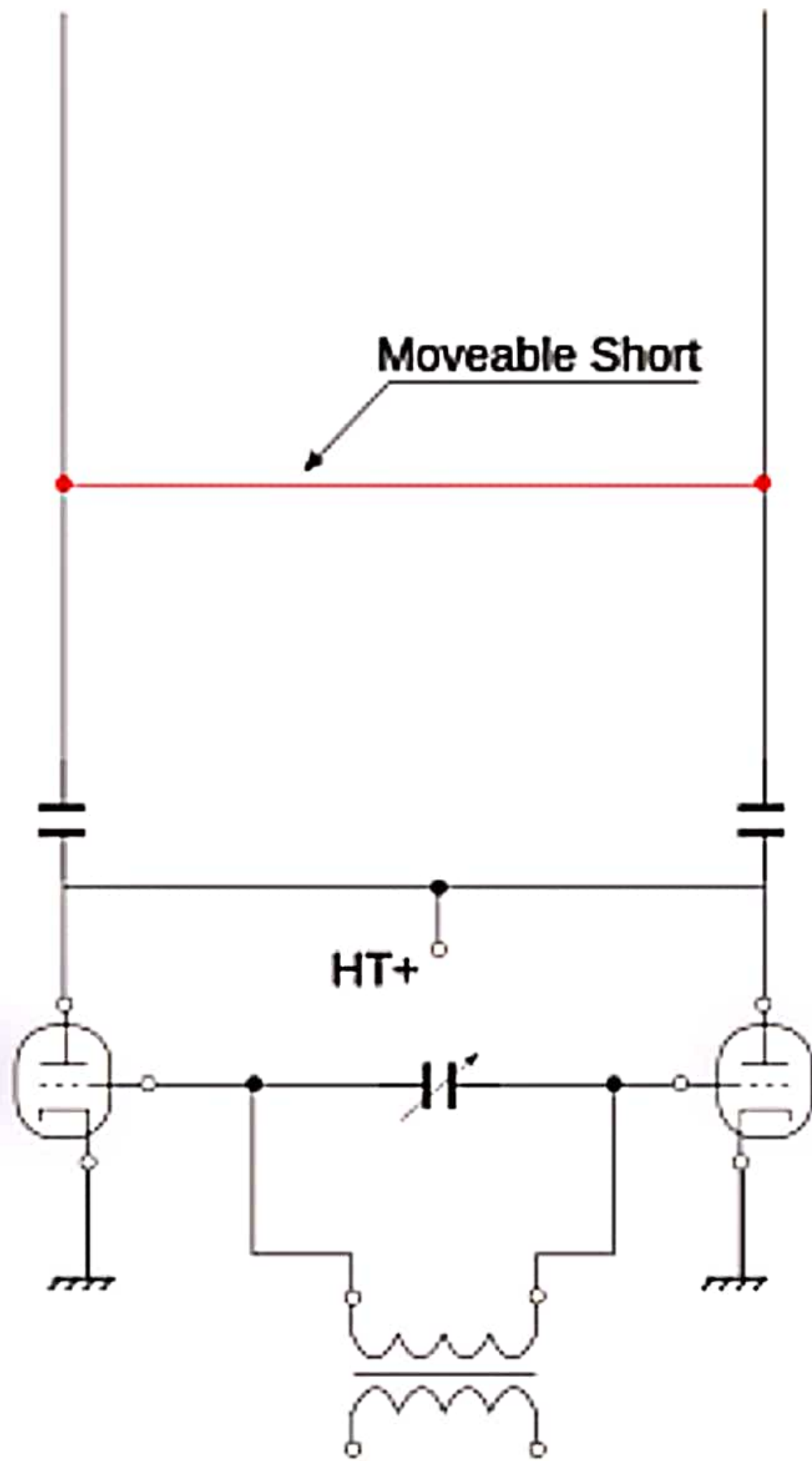


Fig. Lecher wire apparatus

Object :- To determine dielectric constant of a specimen (Liquid) at high frequency by Lecher wires.

Apparatus :- Lecher wire, Detector, Condenser, wooden scale, VHF oscillator.

Theory :- A high frequency power oscillator is inductively coupled to a pair of parallel conducting wires called Lecher wires. The difference between incident and reflected wave from the terminating ends of wire form standing waves. The field strength is maxima at nodes and minima at antinodes however if a capacitor is connected across the free ends of lines then the positions of nodes and antinodes change as a result of change in h.c of the Lecher lines. Such a change occurs on immersing the capacitor in dielectric specimen. The value of dielectric constant at ultra high frequency is determined on the basis of experimental set up is a tuned grid-tuned anode oscillator with proper feedback through grid anode capacity.

$$E = \frac{\lambda_d^2 - \lambda_0^2}{\lambda_a^2 - \lambda_0^2}$$

where λ_0 is the wavelength of standing wave on Lecher lines with lines in air only. λ_d is the wavelength of standing wave on Lecher lines with air capacitor at the terminal ends.

Calculation :-

$$E = \frac{d_d^2 - d_o^2}{d_a^2 - d_o^2}$$

$$= \frac{(88)^2 - (40)^2}{(66)^2 - (40)^2}$$

$$= \frac{7744 - 1600}{4356 - 1600}$$

$$= \frac{6144}{2756}$$

$$= \boxed{2.22}$$

Result :-

di-electric constant of Liquid - 2.22

Precautions: 4

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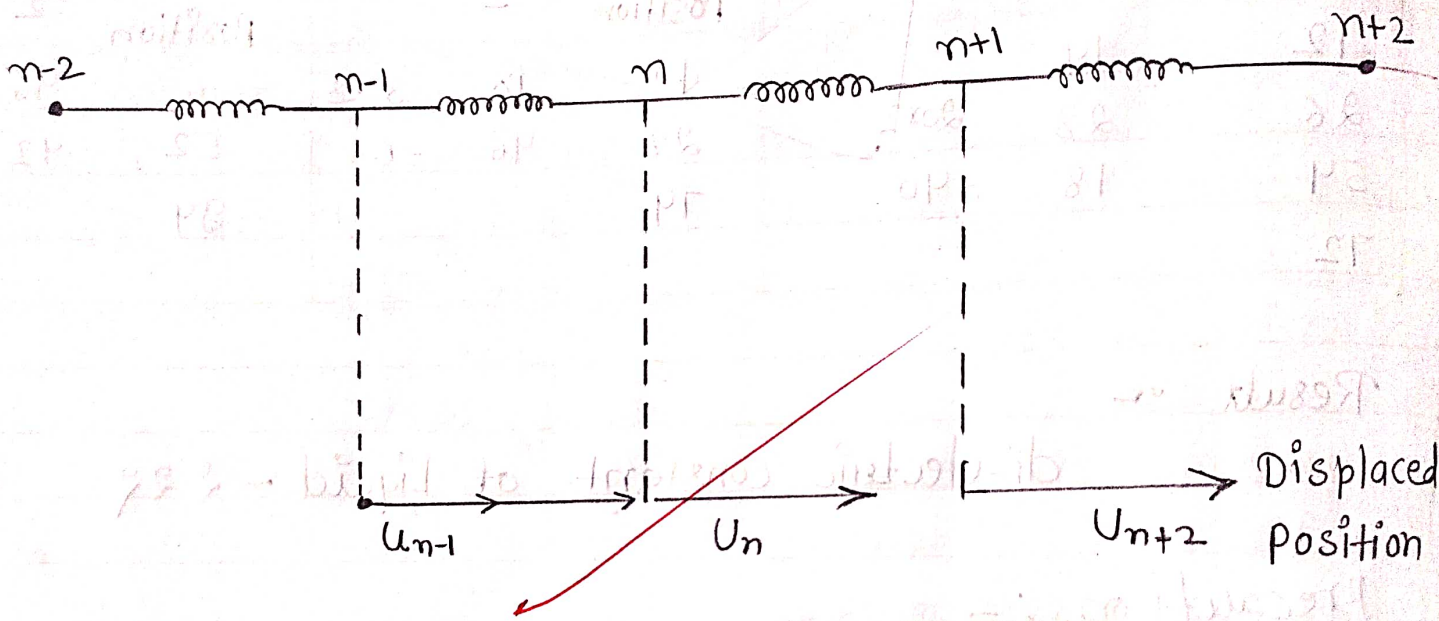
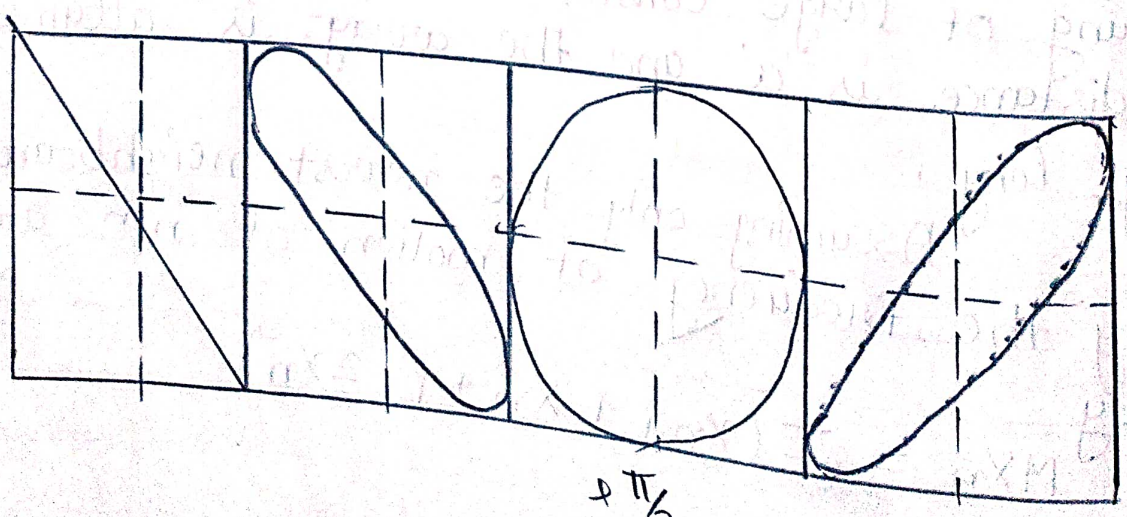
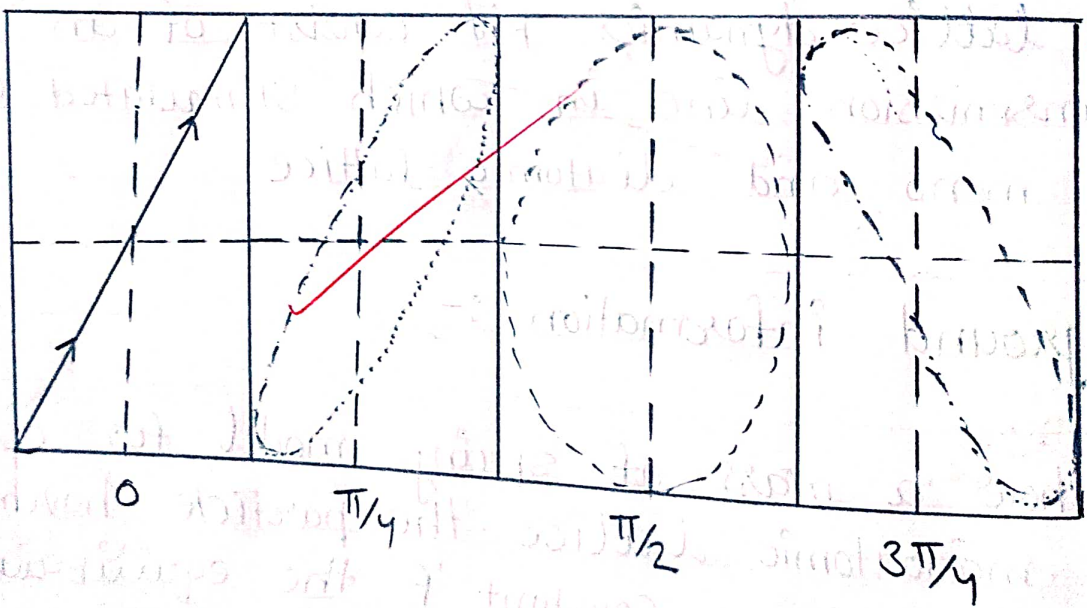
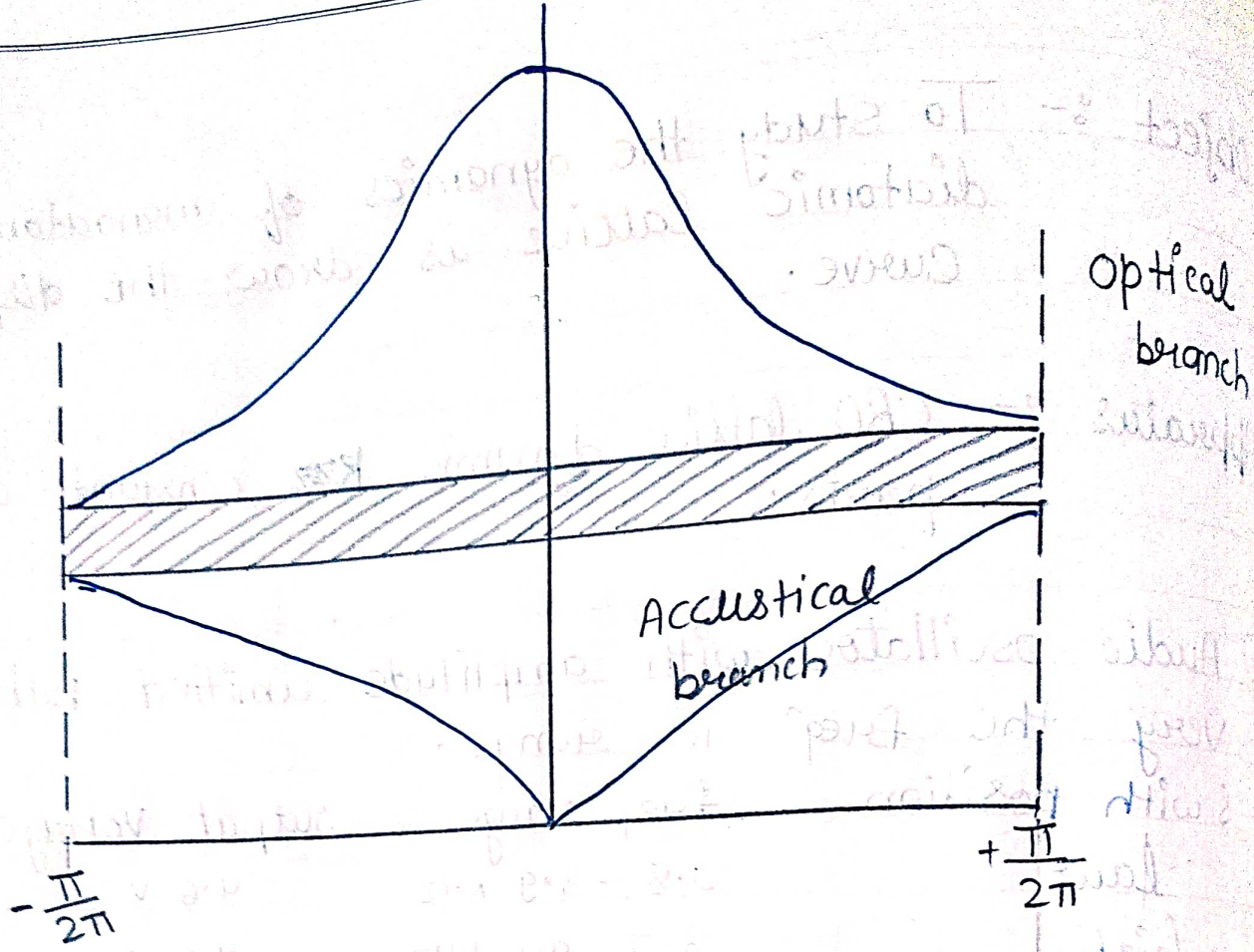


Fig - one dimensional linear monoatomic lattice

a = lattice constant

K = force constant

m = mass of atom



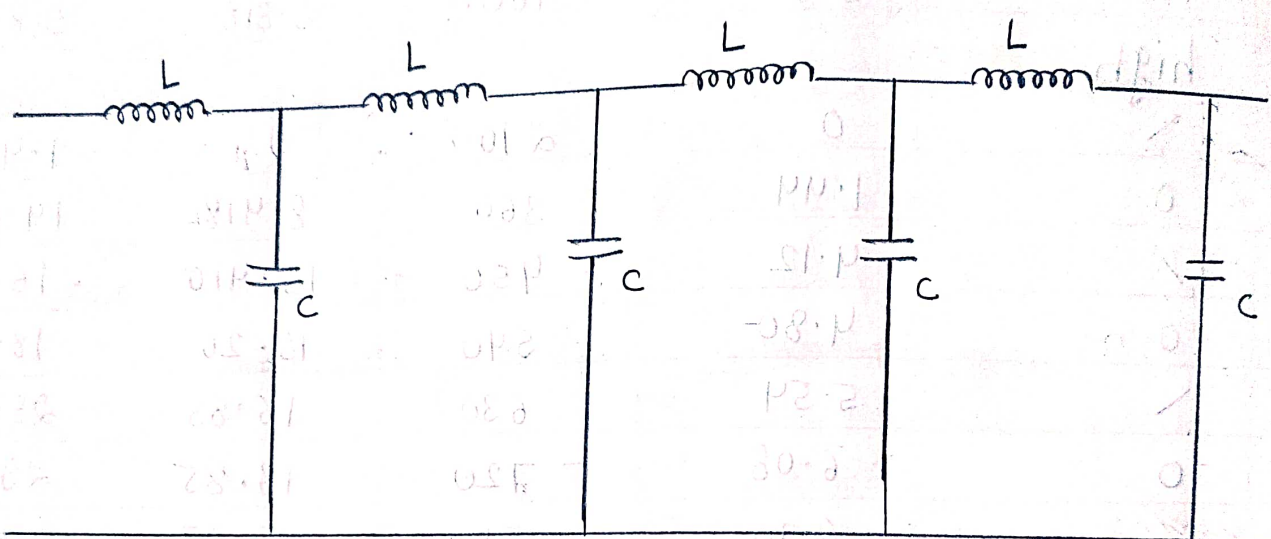
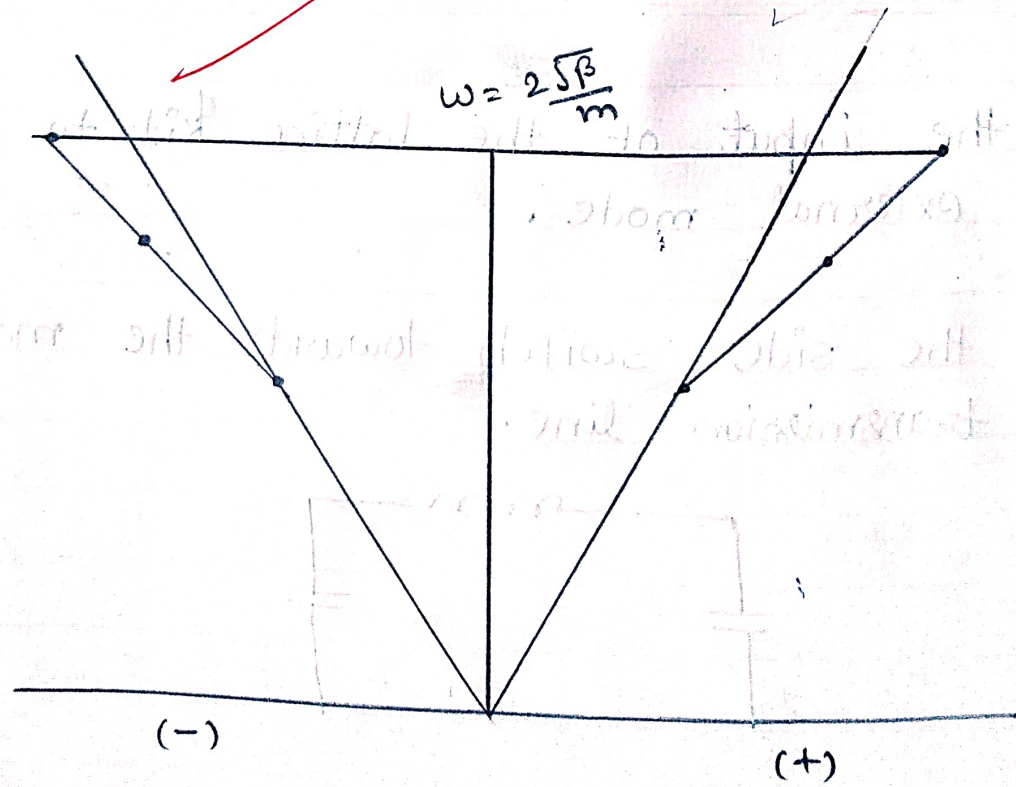


fig :- electrical analog of linear monoatomic



The graph b/w ω & K

Object :- To study the dynamics of monoatomic & diatomic lattice is draw the dispersion Curve.

Apparatus :- CRO, lattice dynamic constant of following parts.

① Audio oscillator with amplitude limited following to vary the freqⁿ in range.

law with position	freq ⁿ range	output voltage
low	0.8 - 8.9 KHz	4.6 v
high	8.7 - 9.1 KHz	4.6 v

② The lattice dynamics kid consist of an electrical transmission line in which stimulated one dimensional mono and diatomic lattice

Back ground information :-

fig(a) show a mass of spring model for a one dimensional monoatomic lattice. the particle have mols connected by spring of large constant 'F' the equilibrium distance b/w distance is 'a' and the array is attumed by infinity long.

Assuming only the nearest neighbouring inequality the frequency of motion of nth atom is given by

$$MX_n = I (X_{n-1} + X_{n+1} - 2X_n)$$

which solved when the angular frequency given

$$\omega^2 = \frac{4f}{m} \sin^2 \left(\frac{k a}{2} \right)$$

$$= \frac{2f}{m} (1 - \cos \theta)$$

Phase change per unit cell freq

$$V_{\max} = \frac{\omega_{\max}}{2} = \frac{1}{\pi} \sqrt{\frac{F}{m}}$$

The electrical analogue of the monoatomic lattice is shown in the fig (6) the dispersion of the circuit is.

$$\omega^2 = \frac{2}{LC} (1 - \cos \theta)$$

The diatomic lattice with ~~alternating~~ masses 'm' & 'M' shown in the fig. can be simulated by transmission line.

$$\text{(Mechanical)} \quad \omega^2 = F \left[\frac{1}{m} + \frac{1}{M} \right] \pm \left[F \left(\frac{1}{m} + \frac{1}{M} \right)^2 - \frac{4 \sin^2 \theta}{mM} \right]^{1/2}$$

$$\text{(electrical)} \quad \omega^2 = \left[\frac{1}{L} \left(\frac{1}{C_0} + \frac{1}{C_1} \right) \right] \pm \left[\frac{1}{L} \left(\frac{1}{C} + \frac{1}{C_1} \right)^2 - \frac{4 \sin^2 \theta}{CC_1} \right]^{1/2}$$

There are two frequency ω_+ & ω_- corresponding to a particular value of wave vector k . ω_+ is called optical branch & ω_- is called acoustical branch.

Experimental procedure :-

1. Although the lattice dynamic kit to audio oscillator & plug in the power freqⁿ.

S.NO	CRO Pattern	pial reading	ω	$h\omega$	ω (KHz)	
					obs.	cal.
1.	/	0	0	0	0	0
2.	0	8.34	9	90	3.27	3.64
3.	\	9.34	18	180	5.11	7.24
4.	High					
1.	/	5.00	27	270	0	10.80
2.	0	4.25	36	360	11.38	14.35
3.	\	5.27	45	450	13.85	17.77
4.	0	6.47	54	540	17.46	21.08
5.	/	7.37	63	630	24.76	24.66
6.	0	7.62	72	720	27.59	29.29
7.	\	7.80	81	810	29.26	30.16
8.	0	8.19	90	900	31.35	32.64
9.	/	8.35	99	990	33.50	30.31
10.	0	8.32	108	1080	34.06	37.89

Table :-
for diatomic

$$L = 1.0 \text{ mH}$$

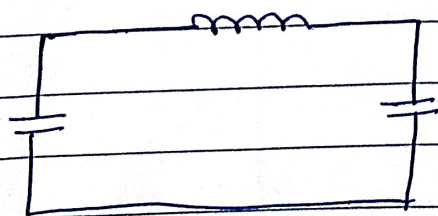
$$C = 0.047 \mu\text{F}$$

$$G = 0.1 \mu\text{F}$$

S.No	CRO Pattern	Dial Reading	θ	frequency	
				Cal.	obs.
1	/	0	0	0	-
2	o	7.31	90	2.418	2.9
3	\	8.66	180	3.318	5.8
4	high				
5	/	0	270	0	1.4
6	o	1.44	360	8.418	14.0
7	/	4.12	450	15.410	16.5
8	o	4.80	540	15.20	18.0
9	\	5.54	630	16.83	28.5
10	o	6.08	720	18.85	29.5
11	/	6.70	810	20.07	29.5
12	o	7.70	900	21.59	33.0

(ii) feed the input of the lattice kit to CRO. the on the external mode.

(iii) Switch the side switch towards the monoatomic side the transmission line.



(iv) Starting with the lowest freqⁿ vary with the frequency of the audio oscillator diatomic the frequency blue

input and output voltage

(v) Represent the observed & calculated value of V as a "freq" of a connected on the agreement b/w the theoretical & practical.

(vi) findout the max. frequency of transmission & compare with theoretical value of $\frac{1}{2} \sqrt{\frac{f}{m}}$

Diatomic lattice -

(i) E up the side switch on the lattice dynamic kit towards to $C_1 = 0.0147 \mu\text{f}$

(ii) Repet the procedure outline for the monoatomic lattice note the existance of energy gap

Calculation :-

① for monoatomic Lattice

$$\omega^2 = \frac{2}{Lc} (1 - \cos\theta)$$

$$\text{then } \gamma = \frac{1}{2\pi} \sqrt{\frac{2}{Lc} (1 - \cos\theta)}$$

$$\gamma = 32.84 \sqrt{1 - \cos\theta} \text{ KHz}$$

(i) at $\theta = 90^\circ$ $\gamma = 32.84 \sqrt{1 - \cos 90^\circ}$
 $\gamma = 3.64 \text{ KHz}$

(ii) at $\theta = 180^\circ$ $\gamma = 32.84 \sqrt{1 - \cos 180^\circ}$
 $\gamma = 7.2 \text{ MHz}$

② for diatomic lattice

$$\omega^2 = \frac{1}{L} \left[\frac{1}{c} + \frac{1}{c_1} \right] + \frac{1}{L} \left[\frac{1}{c} + \frac{1}{c_1} \right]^2 - \frac{4 \sin^2 \theta}{Lc_1}$$

$$\omega^2 = \frac{1}{2\pi} \sqrt{\frac{1}{L} \left(\frac{1}{c} + \frac{1}{c_1} \right) + \frac{1}{L} \left(\frac{1}{c} + \frac{1}{c_1} \right)^2 - \frac{4 \sin^2 \theta}{Lc_1}}$$

Similarly from eqⁿ ② calculate freqⁿ diff. angle;

Result :-

- (i) for monoatomic lattice dispersion curve b/w freqⁿ calculated and observed a phase difference ϕ is almost same for theoretical and optical value.
- (ii) for diatomic lattice vibration curve consist of two branch optical which is upper part is the acoustical branch. the difference b/w these parts

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are branchless towards as forbidden frequency gap
the graph for experiment & theoretical value is
almost same.

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